QDLASER

QLF063A/QLF063D

660 nm 100mW FP LASER TO-CAN

C00100-02 April 2016



1. DESCRIPTION

The QLF063A/QLF063D are 660 nm quantum well laser devices designed for high output power application. The laser diode is mounted into a TO-56 header including a monitor PD and hermetic sealed with a flat glass cap.

2. FEATURES

- 660 nm FP-LD
- Φ5.6mm TO-CAN package
- High output power of 100mW and high slope efficiency
- Including monitor PD
- Two types of pin assignments: anode common type (QLF063A)/cathode common type (QLF063D)

3. APPLICATIONS

- Industrial laser markers
- Measuring instruments
- Life science applications

4. ABSOLUTE MAXIMUM RATING

(CW operation, $T_c = 25$ °C, unless otherwise specified)

	peration, $T_{\xi} = 25$ C, unless otherwise specific		
PARAMETER	SYMBOL	RATING	UNIT
Optical output power	Po	130	mW
	P _o (Pulse) *	300	mW
LD reverse voltage	V_{RLD}	2	V
PD reverse voltage	V_{RPD}	30	V
Operation temperature	T _c	-10 to 60	°C
Storage temperature	T _{stg}	-40 to 85	°C

^{*} Pluse condition, Pulse width:100nsec, Duty:50%



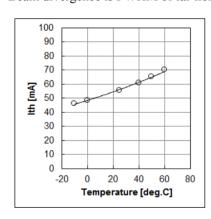
QLF063A/QLF063D C00100-02

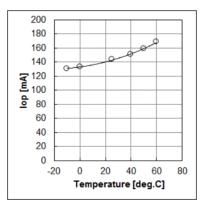
5. OPTICAL AND ELECTRICAL CHARACTERISTICS

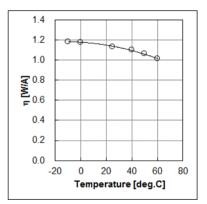
 $(T_c = 25^{\circ}C, unless otherwise specified)$

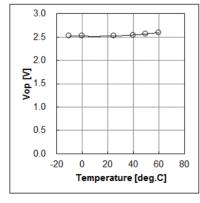
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PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Threshold current	${ m I_{th}}$	CW	-	55	70	mA
Operation current	I_{op}	CW, P _o =100 mW	-	145	200	mA
Operation voltage	V_{op}	CW, P _o =100 mW	-	2.5	3.0	V
Slope efficiency	η	CW, P _o =5 - 100 mW	0.8	1.1	-	W/A
Monitor current	I_{m}	CW , $P_o=100 \text{ mW}$, $V_{RD}=5 \text{ V}$	50	190	600	μА
Peak wavelength	$\lambda_{ m p}$	CW, P _o =100 mW	655	660	665	nm
Beam divergence* Horizontal	θ_{h}	CW, P _o =100 mW	7	10	13	deg.
Beam divergence* vertical	$\theta_{ m v}$	CW, P _o =100 mW	11	14	17	deg.
Beam angle Horizontal	$\Delta heta_{ m h}$	CW, P _o =100 mW	-3	-	3	deg.
Beam angle vertical	$\Delta heta_{ m v}$	CW, P _o =100 mW	-3	-	3	deg.
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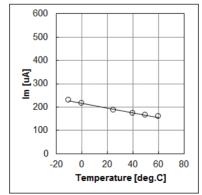
^{*}Beam divergence is FWHM of far field pattern.

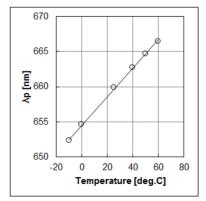






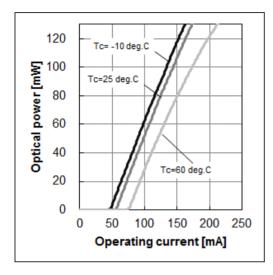


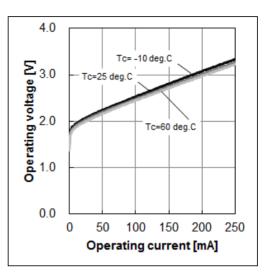


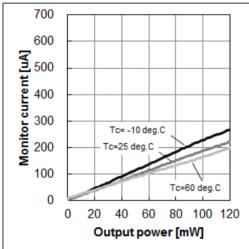


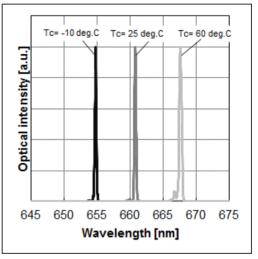


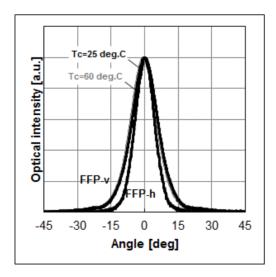
QLF063A/QLF063D C00100-02







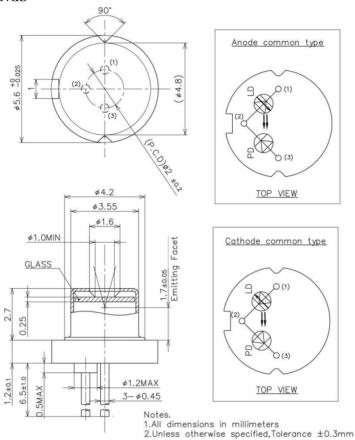






OLF063A/OLF063D

6. OUTLINE DRAWINGS



7. NOTICE

• Safety Information

This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10. Please do not take a look laser lighting in operations since laser devices may cause troubles to human eyes. Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

• Handling products

Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD.

Please pay attention to handling products, and use within range of maximum ratings.

QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

RoHS

This product conforms to RoHS compliance related EU Directive 2011/65/EU.

QD Laser, Inc.

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